NSN 5961-01-030-8064

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View Online at https://aerobasegroup.com/nsn/5961-01-030-8064 **Inclosure Material:** Metal **Overall Length:** Between 0.390 inches and 0.450 inches **Overall Height:** Between 0.070 inches and 0.130 inches Overall Width: Between 0.270 inches and 0.330 inches **End Application:** Anfsq111 **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 375.0 breakdown voltage, collector-to-base, emitter open and 350.0 breakdown voltage, collector-to-emitter, base open and 6.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 250.00 milliamperes source cutoff current and 500.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 20.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 165.0 degrees celsius junction **Special Features:** Heat sink included; junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin **Specification Data:** 80131-release6050 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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No